

**MDA970A1
thru
MDA970A6**

Designers Data Sheet

INTEGRAL DIODE ASSEMBLIES

... diffused silicon dice interconnected and transfer molded into rectifier circuit assemblies for use in application where high output current/size ratio is of prime importance. These devices feature:

- Void-free, Transfer-molded Encapsulation to Assure High Resistance to Shock, Vibration, and Temperature Extremes
- High Dielectric Strength
- Simple, Compact Structure for Trouble-free Performance
- High Surge Capability — 100 Amps

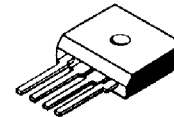
Designers Data for "Worst Case" Conditions

The Designers Data Sheet permits the design of most circuits entirely from the information presented. Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.



**SINGLE-PHASE
FULL-WAVE BRIDGE**

**4 AMPERES
50-600 VOLTS**



MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	MDA970A1	MDA970A2	MDA970A3	MDA970A5	MDA970A6	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{VRWM} V _R	50	100	200	400	600	Volts
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	Volts
DC Output Voltage Resistive Load Capacitive Load	V _{dc} V _{dc}	31 50	62 100	124 200	248 400	372 600	Volts
Average Rectified Forward Current T _A = 25°C T _C = 55°C	I _O	←————— 4.0 —————→ ←————— 8.0 —————→					Amp
Nonrepetitive Peak Surge Current (surge applied at rated load conditions, T _J = 150°C)	I _{FSM}	←————— 100 —————→					Amp
Operating and Storage Junction Temperature Range	T _J , T _{stg}	←————— -65 to +150 —————→					°C

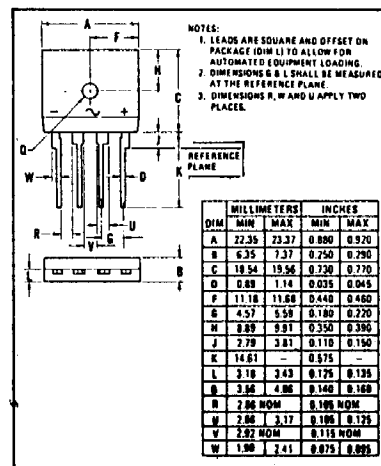
THERMAL CHARACTERISTICS

Characteristics	Symbol	Max (Per Die)	Unit
Thermal Resistance, Junction to Case	R _{θJC}	10	°C/W
Effective Bridge	R _{θ(EFF)}	7.75	°C/W

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Max	Unit
Instantaneous Forward Voltage (Per Diode) (I _F = 6.28 Amp, T _J = 25°C) (I _F = 6.28 Amp, T _J = 150°C)	V _F	—	1.1 1.0	V _{dc}
Reverse Current (Rated V _{RM} applied to ac terminals, + and - terminals open, T _A = 25°C)	I _R	—	1.0	mA

CASE: Transfer-molded plastic encapsulation.
FINISH: All external surfaces are corrosion-resistant. Leads are readily solderable.
POLARITY: Embossed symbols
AC input = ~ DC output = + DC output = -
MOUNTING POSITION: Any
WEIGHT (Approximately): 7.5 Grams
MOUNTING TORQUE: 5 in.-lb. Max



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